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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR



2SK3640

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3640 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3640-ZK	TO-252 (MP-3ZK)

FEATURES

· Low on-state resistance

 $R_{DS(on)1}$ = 21 $m\Omega$ MAX. (Vgs = 10 V, ID = 9 A)

 $R_{DS(on)2} = 40 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A})$

- Low Ciss: Ciss = 570 pF TYP.
- · Built-in gate protection diode

(TO-252)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage (Vss = 0 V)	VDSS	30	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±16	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±19	Α
Drain Current (pulse) Note1	$I_{D(pulse)}$	±76	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	20	W
Total Power Dissipation	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	10	Α
Single Avalanche Energy Note2	Eas	10	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 15 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = 20 \rightarrow 0 V

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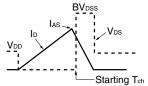


ELECTRICAL CHARACTERISTICS (TA = 25°C)

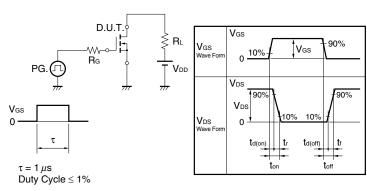
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V _{DS} = 30 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±16 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 9 A	3.7	7.4		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 9 A		15	21	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 9 A		24	40	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		570		pF
Output Capacitance	Coss	Ves = 0 V		160		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		100		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 9 A		7.7		ns
Rise Time	t r	V _{GS} = 10 V		4.7		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		24		ns
Fall Time	tf			7		ns
Total Gate Charge	Q _G	V _{DD} = 24 V		14		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		2.4		nC
Gate to Drain Charge	Q _{GD}	I _D = 19 A		4.3		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 19 A, V _{GS} = 0 V		0.95		V
Reverse Recovery Time	t rr	I _F = 19 A, V _{GS} = 0 V		21		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		12		nC

Note Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2%

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

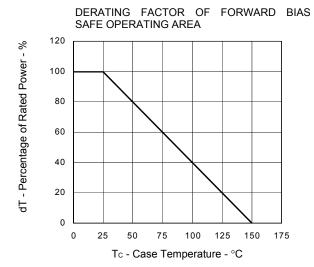


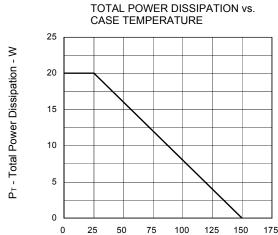
TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline WV \\ \hline \end{array}$$

$$\begin{array}{c|c} PG. \\ \hline \end{array} \begin{array}{c} S50 \ \Omega \\ \hline \end{array} \begin{array}{c} V_{DD} \\ \hline \end{array}$$

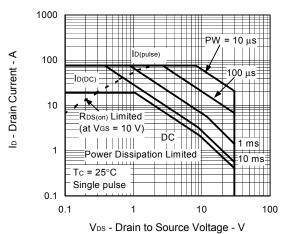
TYPICAL CHARACTERISTICS (TA = 25°C)



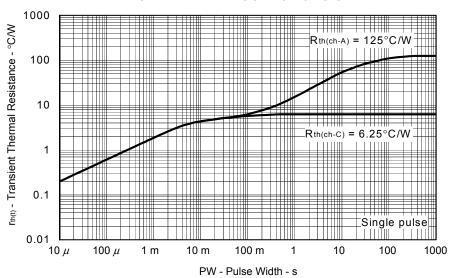


Tc - Case Temperature - °C

FORWARD BIAS SAFE OPERATING AREA



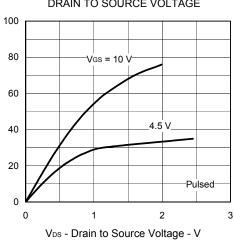
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



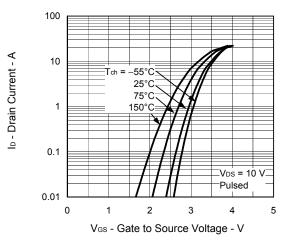
lo - Drain Current - A

VGS(off) - Gate Cut-off Voltage - V

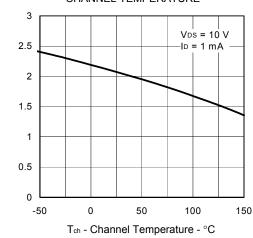
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



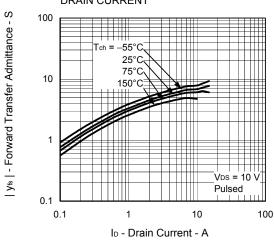
FORWARD TRANSFER CHARACTERISTICS



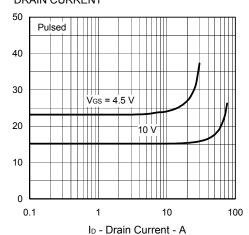
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



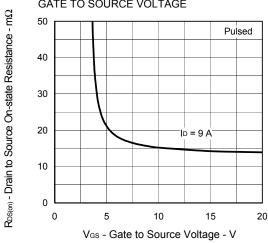
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



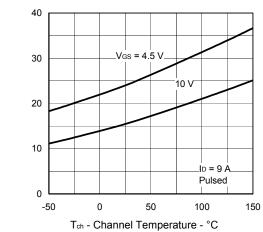
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



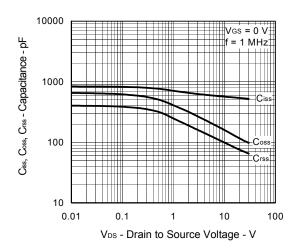
RDS(m) - Drain to Source On-state Resistance - mΩ

RDS(on) - Drain to Source On-state Resistance - m\Omega

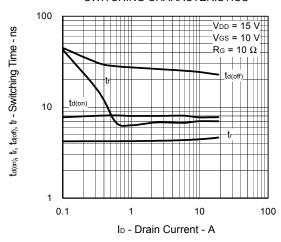
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



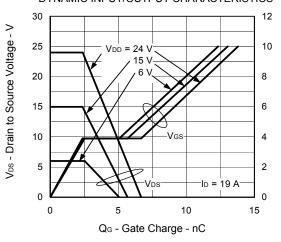
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



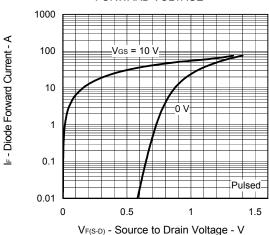
SWITCHING CHARACTERISTICS



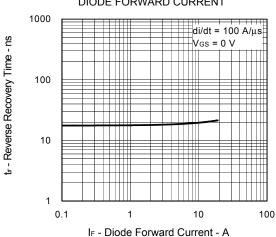
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

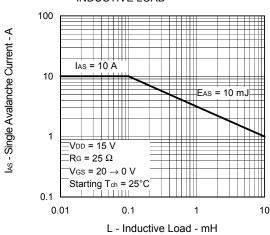


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

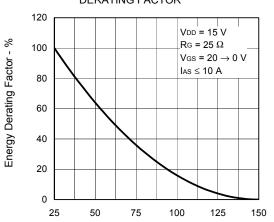


Ves - Gate to Source Voltage - V

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR

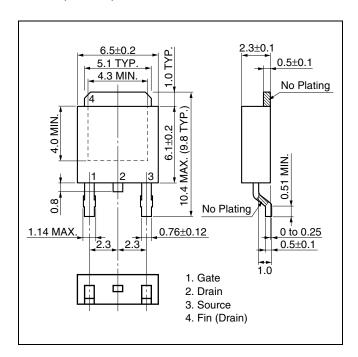


Starting Tch - Starting Channel Temperature - °C

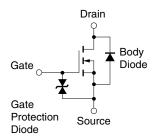


★ PACKAGE DRAWING (Unit: mm)

TO-252 (MP-3ZK)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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